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1 Electrical ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit	
V _{DS}	Drain-source voltage (V _{GS} = 0)	60	V	
V _{DGR}	Drain-gate voltage (R_{GS} = 20 kΩ)	60	V	
V _{GS}	Gate- source voltage	± 18	V	
I _D	Drain current (continuous) at T _C = 25°C	24	Α	
I _D	Drain current (continuous) at T _C = 100°C	17	Α	
I _{DM} ⁽¹⁾	Drain current (pulsed)	96	А	
P _{tot}	Total dissipation at T _C = 25°C	40	W	
	Derating Factor	0.27	W/°C	
dv/dt ⁽²⁾	Peak diode recovery avalanche energy	11.5	V/ns	
E _{AS} (3)	Single pulse avalanche energy	200	mJ	
T _{stg}	Storage temperature	-55 to 175 °C		
Tj	Max. operating junction temperature	-55 to 175		

^{1.} Pulse width limited by safe operating area.

Table 2. Thermal data

Rthj-case	Rthj-case Thermal resistance junction-case max			
Rthj-pcb	Thermal resistance junction-to PCB max	62	°C/W	
TJ	Maximum lead temperature for soldering purpose (1)	300	°C	

^{1.} When Mounted on 1 inch2 FR-4 board, 2 oz. of Cu.

^{2.} $I_{SD} \leq 6A$, di/dt $\leq 200A/\mu s$, $V_{DD} = V(BR)DSS$, $T_j \leq T_{JMAX}$

^{3.} Starting $T_j = 25$ °C, $I_D = 20A$, $V_{DD} = 48V$

2 Electrical characteristics

(T_{CASE}=25°C unless otherwise specified)

Table 3. On/off states

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)DSS}	Drain-source breakdown voltage	$I_D = 250 \mu A, V_{GS} = 0$	60			V
I _{DSS}	Zero gate voltage drain current (V _{GS} = 0)	V_{DS} = Max rating V_{DS} = Max rating, T_{C} = 125°C			1 10	μ Α μ Α
I _{GSS}	Gate-body leakage current (V _{DS} = 0)	V _{GS} = ± 18V			±100	nA
V _{GS(th)}	Gate threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1			V
R _{DS(on)}	Static drain-source on resistance	$V_{GS} = 10V, I_D = 8A$ $V_{GS} = 5V, I_D = 8A$		0.060 0.070	0.070 0.085	Ω Ω

Table 4. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
9 _{fs} (1)	Forward transconductance	$V_{DS} = 15V_{,} I_{D} = 12A$		12		S
C _{iss} C _{oss} C _{rss}	Input capacitance Output capacitance Reverse transfer capacitance	$V_{DS} = 25V, f = 1MHz,$ $V_{GS} = 0$		370 69 30		pF pF pF
$\begin{array}{c} t_{d(on)} \\ t_{r} \\ t_{d(off)} \\ t_{f} \end{array}$	Turn-on delay time Rise time Turn-off delay time Fall time	V_{DD} = 30V, I_D = 8A R_G = 4.7 Ω V_{GS} = 5V (see <i>Figure 13</i>)		12 30 20 6		ns ns ns
Q _g Q _{gs} Q _{gd}	Total gate charge Gate-source charge Gate-drain charge	V_{DD} = 30V, I_D = 8A, V_{GS} = 5V, R_G = 4.7 Ω (see <i>Figure 14</i>)		7.5 2.5 4.2		nC nC nC

^{1.} Pulsed: Pulse duration = 300 μ s, duty cycle 1.5%.

Table 5. Source drain diode

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{SD}	Source-drain current Source-drain current (pulsed)				16 64	A A
V _{SD} ⁽²⁾	Forward on voltage	I _{SD} = 16A, V _{GS} = 0			1.5	V
t _{rr} Q _{rr} I _{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	$I_{SD} = 16A$, di/dt = 100A/ μ s, $V_{DD} = 25V$, $T_{j} = 150$ °C (see <i>Figure 15</i>)		53 85 3.2		ns μC A

^{1.} Pulse width limited by safe operating area.

^{2.} Pulsed: Pulse duration = 300 μ s, duty cycle 1.5%

Electrical characteristics (curves) 2.1

Figure 1. Safe operating area

Figure 2. Thermal impedance

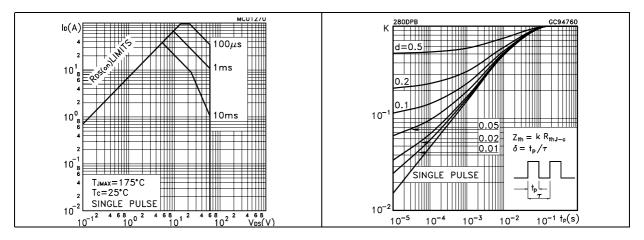


Figure 3. **Output characteristics**

Figure 4. **Transfer characteristics**

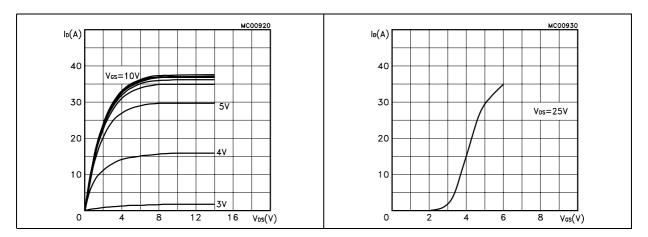


Figure 5. **Transconductance**

Static drain-source on resistance

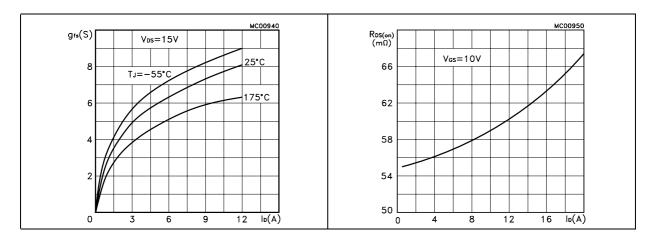


Figure 7. Gate charge vs. gate-source voltage Figure 8. Capacitance variations

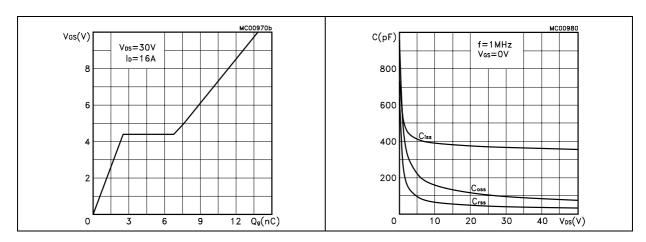


Figure 9. Normalized gate threshold voltage vs. temperature

Figure 10. Normalized on resistance vs. temperature

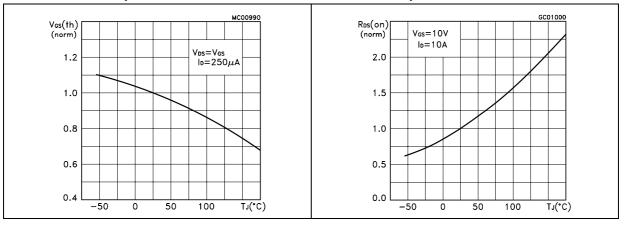
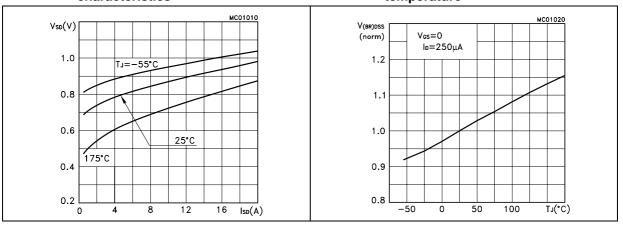


Figure 11. Source-drain diode forward characteristics

Figure 12. Normalized breakdown voltage vs. temperature



3 Test circuit

Figure 13. Switching times test circuit for resistive load

Figure 14. Gate charge test circuit

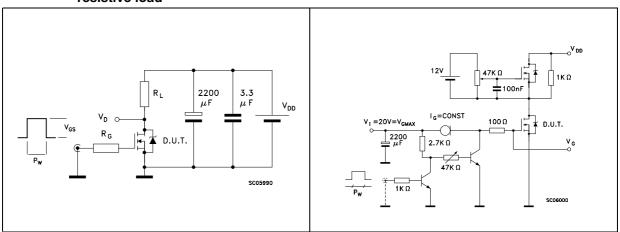


Figure 15. Test circuit for inductive load switching and diode recovery times

Figure 16. Unclamped Inductive load test circuit

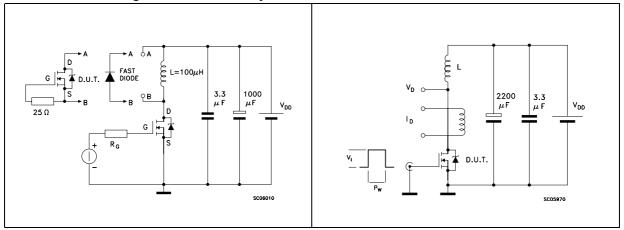
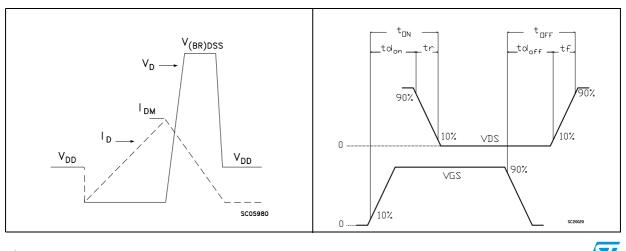


Figure 17. Unclamped inductive waveform

Figure 18. Switching time waveform

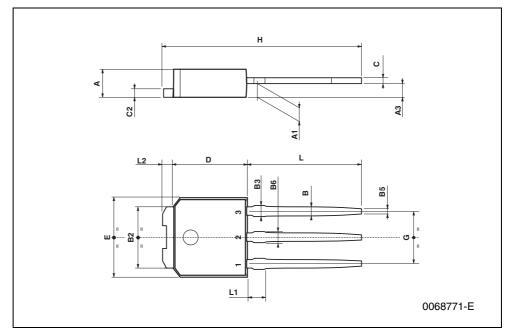


4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-251 (IPAK) MECHANICAL DATA

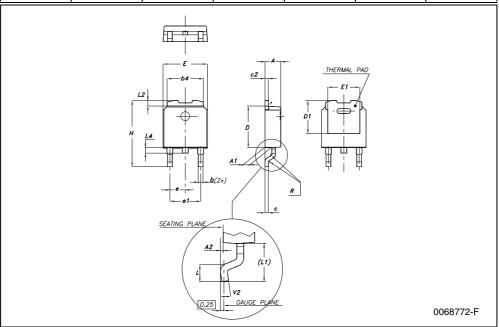
DIM.		mm				
DIIVI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
A3	0.7		1.3	0.027		0.051
В	0.64		0.9	0.025		0.031
B2	5.2		5.4	0.204		0.212
B3			0.85			0.033
B5		0.3			0.012	
B6			0.95			0.037
С	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
E	6.4		6.6	0.252		0.260
G	4.4		4.6	0.173		0.181
Н	15.9		16.3	0.626		0.641
L	9		9.4	0.354		0.370
L1	0.8		1.2	0.031		0.047
L2		0.8	1		0.031	0.039



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DPAK MECHANICAL DATA

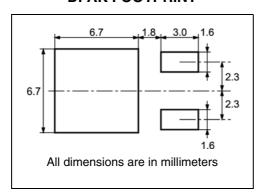
D.114	DIM		mm.			inch	
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α	2.2		2.4	0.086		0.094	
A1	0.9		1.1	0.035		0.043	
A2	0.03		0.23	0.001		0.009	
В	0.64		0.9	0.025		0.035	
b4	5.2		5.4	0.204		0.212	
С	0.45		0.6	0.017		0.023	
C2	0.48		0.6	0.019		0.023	
D	6		6.2	0.236		0.244	
D1		5.1			0.200		
Е	6.4		6.6	0.252		0.260	
E1		4.7			0.185		
е		2.28			0.090		
e1	4.4		4.6	0.173		0.181	
Н	9.35		10.1	0.368		0.397	
L	1			0.039			
(L1)		2.8			0.110		
L2		0.8			0.031		
L4	0.6		1	0.023		0.039	
R		0.2			0.008		
V2	0°		8°	0°		8°	



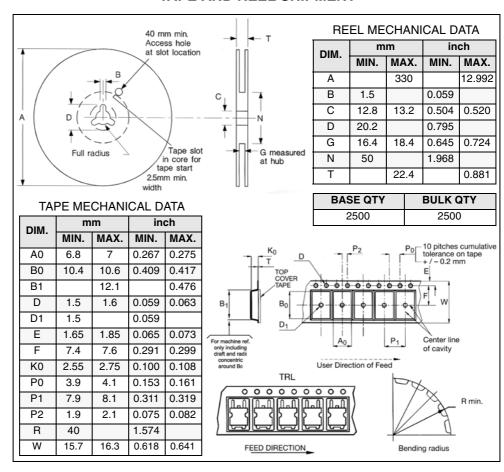
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5 Packing mechanical data

DPAK FOOTPRINT



TAPE AND REEL SHIPMENT



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6 Revision history

Table 6. Revision history

Date	Revision	Changes
28-Feb-2005	1	Initial release
03-Mar-2005	2	Preliminary version
29-Nov-2005	3	Added package IPAK
03-Jul-2006	4	New template, no content change
19-Feb-2007	5	Typo mistake on page 1

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